Matter No.: 10559-587001

Applicant(s): Been-Yih Jin et al.

NON-SILIC EMICONDUCTOR AND HIGH-K GATE
DIELECTRIC METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS



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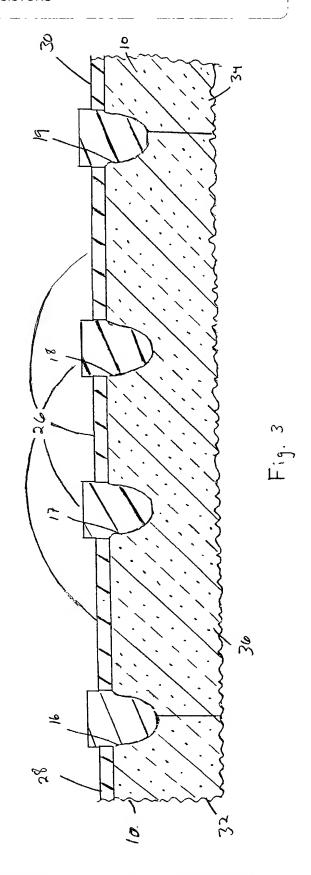
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NON-SIL

SEMICONDUCTOR AND HIGH-K GATE
DIELECTIVE METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS





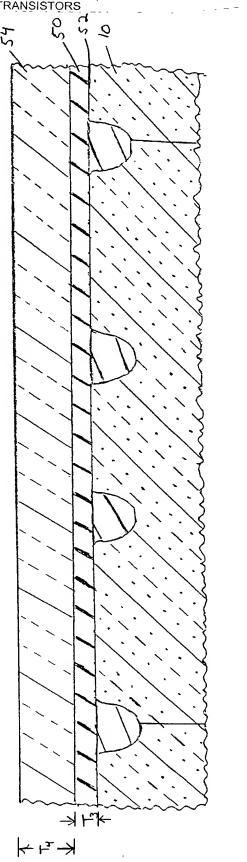
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NEW SILICON SEMICONDUCTOR AND HIGH-K CONSECTRIC METAL OXIDE SEMICONDUCTOR FILE

EFFECT TRANSISTORS



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NON-SILIG SEMICONDUCTOR AND HIGH-K GATE
DIELECTRIS METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS



